# PEMH11; PUMH11

# NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

Rev. 6 — 29 November 2011

Product data sheet

### 1. Product profile

#### 1.1 General description

NPN/NPN Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

| Type number |        |       | NPN/PNP    | PNP/PNP    | Package                   |
|-------------|--------|-------|------------|------------|---------------------------|
|             | NXP    | JEITA | complement | complement | configuration             |
| PEMH11      | SOT666 | -     | PEMD3      | PEMB11     | ultra small and flat lead |
| PUMH11      | SOT363 | SC-88 | PUMD3      | PUMB11     | very small                |

#### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

#### 1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

#### 1.4 Quick reference data

Table 2. Quick reference data

| Symbol      | Parameter                 | Conditions | Min | Тур | Max | Unit |
|-------------|---------------------------|------------|-----|-----|-----|------|
| Per transis | tor                       |            |     |     |     |      |
| $V_{CEO}$   | collector-emitter voltage | open base  | -   | -   | 50  | V    |
| Io          | output current            |            | -   | -   | 100 | mA   |
| R1          | bias resistor 1 (input)   |            | 7   | 10  | 13  | kΩ   |
| R2/R1       | bias resistor ratio       |            | 0.8 | 1   | 1.2 |      |



NPN/NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 10 kΩ

### 2. Pinning information

Table 3. Pinning

| iabic o. | 9                      |                    |                       |
|----------|------------------------|--------------------|-----------------------|
| Pin      | Description            | Simplified outline | Graphic symbol        |
| 1        | GND (emitter) TR1      |                    |                       |
| 2        | input (base) TR1       | 6   5   4          | 6 5 4                 |
| 3        | output (collector) TR2 |                    |                       |
| 4        | GND (emitter) TR2      |                    | R1   R2   R2          |
| 5        | input (base) TR2       |                    | TR1 TR2               |
| 6        | output (collector) TR1 | 001aab555          | R2 R1 R1 1 2 3 sym063 |

### 3. Ordering information

Table 4. Ordering information

| Type number | Package | Package                                  |         |  |
|-------------|---------|--|---------|--|
|             | Name    | Description                              | Version |  |
| PEMH11      | -       | plastic surface-mounted package; 6 leads | SOT666  |  |
| PUMH11      | SC-88   | plastic surface-mounted package; 6 leads | SOT363  |  |

### 4. Marking

Table 5. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| PEMH11      | H1              |
| PUMH11      | H*1             |

<sup>[1] \* =</sup> placeholder for manufacturing site code.

### 5. Limiting values

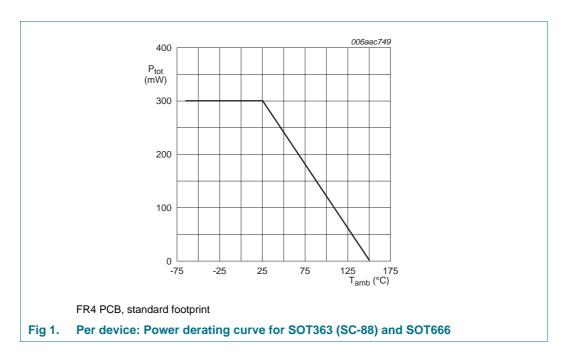
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                 | Conditions                  | Min        | Max  | Unit |
|------------------|---------------------------|-----------------------------|------------|------|------|
| Per transis      | stor                      |                             |            |      |      |
| $V_{CBO}$        | collector-base voltage    | open emitter                | -          | 50   | V    |
| $V_{CEO}$        | collector-emitter voltage | open base                   | -          | 50   | V    |
| $V_{EBO}$        | emitter-base voltage      | open collector              | -          | 10   | V    |
| VI               | input voltage             |                             |            |      |      |
|                  | positive                  |                             | -          | +40  | V    |
|                  | negative                  |                             | -          | -10  | V    |
| Io               | output current            |                             | -          | 100  | mA   |
| I <sub>CM</sub>  | peak collector current    |                             | -          | 100  | mA   |
| P <sub>tot</sub> | total power dissipation   | $T_{amb} \leq 25 ^{\circ}C$ | <u>[1]</u> |      |      |
|                  | PEMH11 (SOT666)           |                             | [2] _      | 200  | mW   |
|                  | PUMH11 (SOT363)           |                             | -          | 200  | mW   |
| Per device       | )                         |                             |            |      |      |
| P <sub>tot</sub> | total power dissipation   | $T_{amb} \leq 25 ^{\circ}C$ | <u>[1]</u> |      |      |
|                  | PEMH11 (SOT666)           |                             | [2] _      | 300  | mW   |
|                  | PUMH11 (SOT363)           |                             | -          | 300  | mW   |
| Tj               | junction temperature      |                             | -          | 150  | °C   |
| T <sub>amb</sub> | ambient temperature       |                             | -65        | +150 | °C   |
| T <sub>stg</sub> | storage temperature       |                             | -65        | +150 | °C   |

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.



### 6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol        | Parameter                                   | Conditions  | Min        | Тур | Max | Unit |
|---------------|---|-------------|------------|-----|-----|------|
| Per trans     | istor                                       |             |            |     |     |      |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | [1]        |     |     |      |
|               | PEMH11 (SOT666)                             |             | [2] _      | -   | 625 | K/W  |
|               | PUMH11 (SOT363)                             |             | -          | -   | 625 | K/W  |
| Per devic     | e   |             |            |     |     |      |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | <u>[1]</u> |     |     |      |
|               | PEMH11 (SOT666)                             |             | [2] _      | -   | 417 | K/W  |
|               | PUMH11 (SOT363)                             |             | -          | -   | 417 | K/W  |

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

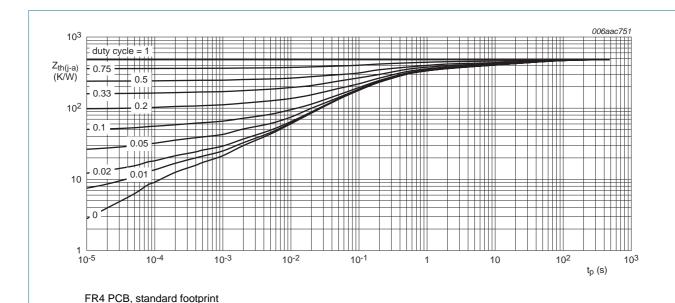


Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PEMH11 (SOT666); typical values

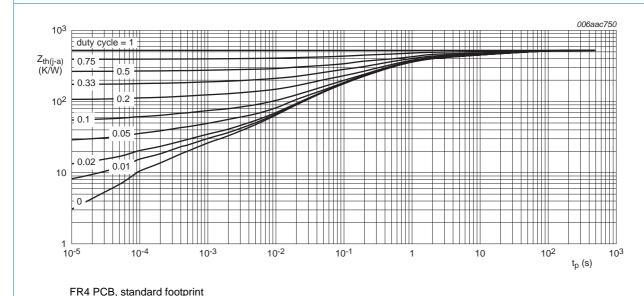


Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PUMH11 (SOT363); typical values

NPN/NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 10 kΩ

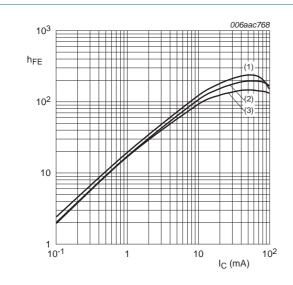
### 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

| Symbol             | Parameter                            | Conditions  | Min   | Тур | Max | Unit |
|--------------------|--------------------------------------|---|-------|-----|-----|------|
| Per trans          | istor                                |   |       |     |     |      |
| I <sub>CBO</sub>   | collector-base cut-off current       | $V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$                                      | -     | -   | 100 | nA   |
| CLO                | collector-emitter                    | $V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$                                    | -     | -   | 1   | μΑ   |
|                    | cut-off current                      | $V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$<br>$T_{j} = 150 ^{\circ}\text{C}$ | -     | -   | 5   | μА   |
| I <sub>EBO</sub>   | emitter-base cut-off current         | $V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$                                     | -     | -   | 400 | μА   |
| h <sub>FE</sub>    | DC current gain                      | $V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$                                    | 30    | -   | -   |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$                                     | -     | -   | 150 | mV   |
| $V_{I(off)}$       | off-state input voltage              | $V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$                                 | -     | 1.1 | 8.0 | V    |
| $V_{I(on)}$        | on-state input<br>voltage            | $V_{CE} = 0.3 \text{ V}; I_{C} = 10 \text{ mA}$                                 | 2.5   | 1.8 | -   | V    |
| R1                 | bias resistor 1 (input)              |   | 7     | 10  | 13  | kΩ   |
| R2/R1              | bias resistor ratio                  |   | 0.8   | 1   | 1.2 |      |
| C <sub>c</sub>     | collector capacitance                | $V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz                     | -     | -   | 2.5 | pF   |
| f <sub>T</sub>     | transition frequency                 | $V_{CB} = 5 \text{ V; } I_{C} = 10 \text{ mA;}$ f = 100 MHz                     | [1] - | 230 | -   | MHz  |

<sup>[1]</sup> Characteristics of built-in transistor.



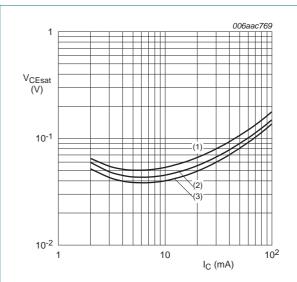
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig 4. DC current gain as a function of collector current; typical values



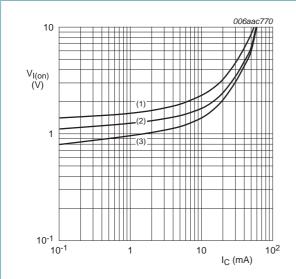
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values



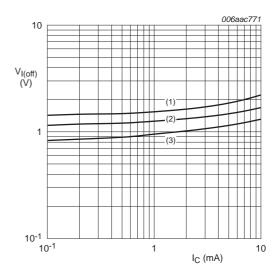
$$V_{CE} = 0.3 \text{ V}$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig 6. On-state input voltage as a function of collector current; typical values



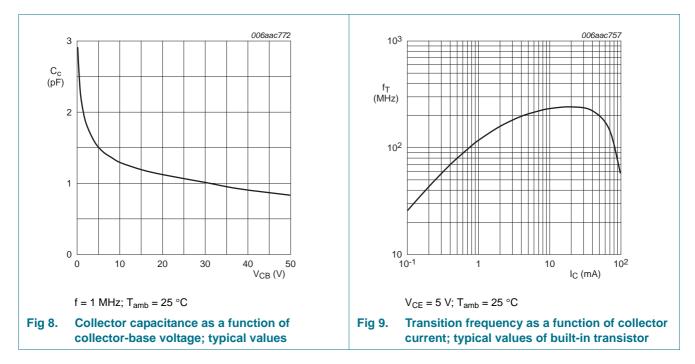
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -40 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig 7. Off-state input voltage as a function of collector current; typical values

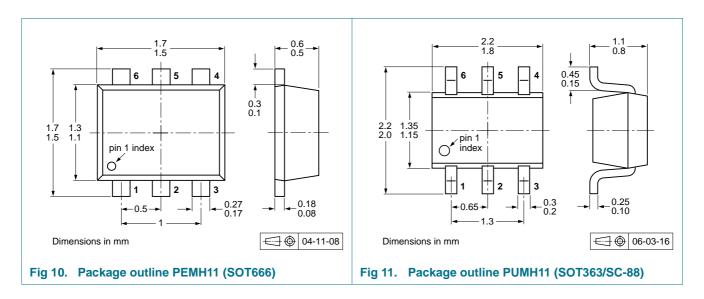


### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



PEMH11\_PUMH11

### 10. Packing information

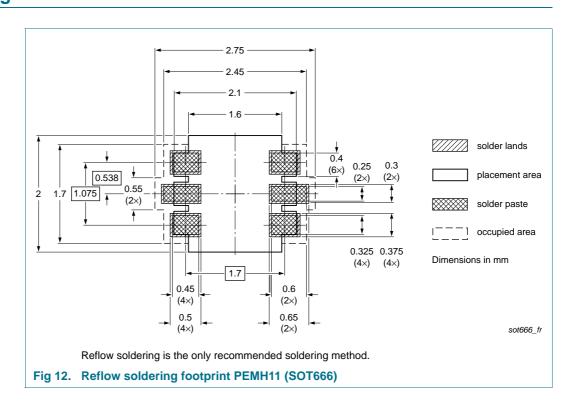
Table 9. Packing methods

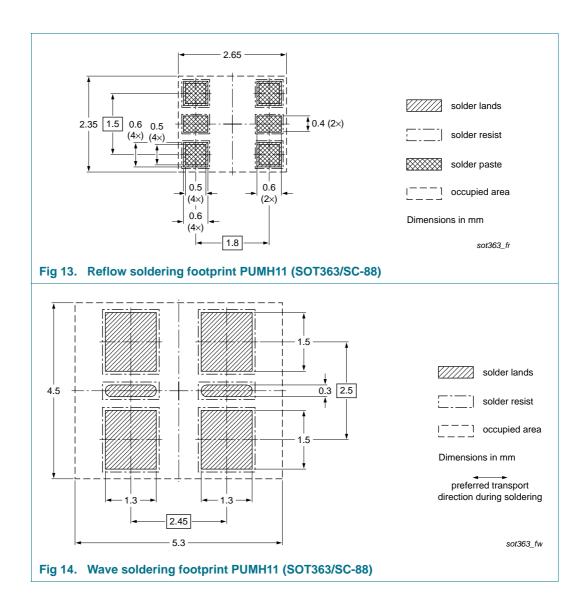
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

|             |         | <u> </u>                           |     |        |         |       |       |
|-------------|---------|------------------------------------|-----|--------|---------|-------|-------|
| Type number | Package | Description                        |     | Packii | ng quar | ntity |       |
|             |         |                                    |     | 3000   | 4000    | 8000  | 10000 |
| PEMH11      | SOT666  | 2 mm pitch, 8 mm tape and reel     |     | -      | -       | -315  | -     |
|             |         | 4 mm pitch, 8 mm tape and reel     |     | -      | -115    | -     | -     |
| PUMH11      | SOT363  | 4 mm pitch, 8 mm tape and reel; T1 | [2] | -115   | -       | -     | -135  |
|             |         | 4 mm pitch, 8 mm tape and reel; T2 | [3] | -125   | -       | -     | -165  |

- [1] For further information and the availability of packing methods, see Section 14.
- [2] T1: normal taping
- [3] T2: reverse taping

### 11. Soldering





NPN/NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 10 kΩ

### 12. Revision history

#### Table 10. Revision history

| Release date   | Data sheet status   | Change notice   | Supersedes   |  |  |  |  |
|--|---|---|--|--|--|--|--|
| 20111129   | Product data sheet  | -   | PEMH11_PUMH11 v.5  |  |  |  |  |
| <ul> <li>The format of this document has been redesigned to comply with the new identity<br/>guidelines of NXP Semiconductors.</li> </ul>  |   |   |  |  |  |  |  |
| <ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>   |   |   |  |  |  |  |  |
| <ul> <li>Section 1 "Product profile": updated</li> </ul>   |   |   |  |  |  |  |  |
| <ul><li>Section 4 "I</li></ul>   | Marking": updated   |   |  |  |  |  |  |
| <ul> <li><u>Table 7 "Thermal characteristics"</u>: updated according to the latest measurements</li> </ul>   |   |   |  |  |  |  |  |
| <ul> <li><u>Table 8 "Characteristics"</u>: I<sub>CEO</sub> updated according to the latest measurements, V<sub>i(on)</sub> and V<sub>i(off)</sub> changed respectively to V<sub>I(on)</sub> and V<sub>I(off)</sub>, f<sub>T</sub> added</li> </ul> |   |   |  |  |  |  |  |
| <ul> <li>Figure 1 to</li> </ul>  | 9: added  |   |  |  |  |  |  |
| Section 8 "Test information": added  |   |   |  |  |  |  |  |
| <ul> <li><u>Figure 10</u> and <u>11</u>: replaced by minimized package outline drawings</li> </ul>   |   |   |  |  |  |  |  |
| <ul> <li>Section 10 "Packing information": added</li> </ul>  |   |   |  |  |  |  |  |
| Section 11 "Soldering": added  |   |   |  |  |  |  |  |
| • Section 13   | "Legal information": updat  | ed  |  |  |  |  |  |
| 20031020   | Product data sheet  | -   | PUMH11 v.4<br>PEMH11 v.1   |  |  |  |  |
| 19990413   | Product specification   | -   | -  |  |  |  |  |
| 20011022   | Preliminary specification   | n -   | -  |  |  |  |  |
|  | 20111129  The format guidelines of Legal texts Section 1 "I Section 4 "I Table 7 "The Table 8 "Che Vi(off) change Figure 1 to Section 8 " Figure 10 a Section 10 Section 11 Section 13 20031020 | <ul> <li>The format of this document has been guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the</li> <li>Section 1 "Product profile": updated</li> <li>Section 4 "Marking": updated</li> <li>Table 7 "Thermal characteristics": updated Vi(off) changed respectively to VI(on) and Figure 1 to 9: added</li> <li>Section 8 "Test information": added</li> <li>Figure 10 and 11: replaced by minimitiating Section 10 "Packing information": added</li> <li>Section 11 "Soldering": added</li> <li>Section 13 "Legal information": update</li> <li>20031020 Product specification</li> </ul> | <ul> <li>20111129 Product data sheet -</li> <li>The format of this document has been redesigned to comguidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company nam</li> <li>Section 1 "Product profile": updated</li> <li>Section 4 "Marking": updated</li> <li>Table 7 "Thermal characteristics": updated according to the laward of the l</li></ul> |  |  |  |  |

### 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
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PEMH11\_PUMH11

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PEMH11; PUMH11

NPN/NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$ 

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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## PEMH11; PUMH11

### NPN/NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 10 kΩ

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